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#### Vishay Semiconductors

## Hyperfast Rectifier, 8 A FRED Pt®



2L TO-220 FullPAK



VS-8ETH06FP-N3

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	8 A			
$V_{R}$	600 V			
V <sub>F</sub> at I <sub>F</sub>	1.3 V			
t <sub>rr</sub> typ.	18 ns			
T <sub>J</sub> max.	175 °C			
Package	2L TO-220 FullPAK			
Circuit configuration	Single			

#### **FEATURES**

- · Hyperfast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- · Low leakage current
- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- UL pending
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Repetitive peak reverse voltage	$V_{RRM}$		600	V
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 108 °C	8	
Non-repetitive peak surge current	I <sub>FSM</sub>		100	Α
Repetitive peak forward current	I <sub>FM</sub>		16	
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-	.,
Forward voltage	V	I <sub>F</sub> = 8 A	-	2.0	2.4	V
Forward voltage V <sub>F</sub>	VF	I <sub>F</sub> = 8 A, T <sub>J</sub> = 150 °C	-	1.3	1.8	
Reverse leakage current I <sub>R</sub>		$V_R = V_R$ rated	-	0.3	50	
		$T_J = 150 ^{\circ}\text{C},  V_R = V_R  \text{rated}$	-	55	500	μA
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	17	-	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	18	22	
Reverse recovery time	+	$I_F = 8 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	20	25	
neverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	$I_F = 8 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 390 \text{ V}$	-	25	-	ns
		T <sub>J</sub> = 125 °C		-	40	-	
Deal massing a massing l	1	T <sub>J</sub> = 25 °C		-	2.4	-	А
Peak recovery current	IRRM	T <sub>J</sub> = 125 °C		-	4.8	-	
Poverse receivery charge	0	T <sub>J</sub> = 25 °C		-	25	-	nC
Reverse recovery charge Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	120	-	110	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 125 °C	$I_F = 8 A$ $dI_F/dt = 600 A/\mu s$ $V_R = 390 V$	-	33	-	ns
Peak recovery current	I <sub>RRM</sub>			-	12	-	Α
Reverse recovery charge	Q <sub>rr</sub>			-	220	-	nC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C
Thermal resistance, junction-to-case	R <sub>thJC</sub>		-	3.4	4.3	°C/W
Thermal resistance, junction-to-ambient per leg	R <sub>thJA</sub>	Typical socket mount	-	-	70	
Thermal resistance, case-to-heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.5	-	
Weight			-	2.0	-	g
vveignt			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style 2L TO-220 FullPAK	8ETH06FP			

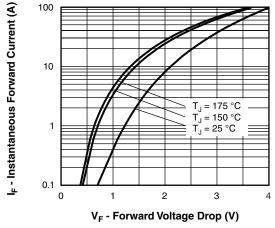


Fig. 1 - Typical Forward Voltage Drop Characteristics

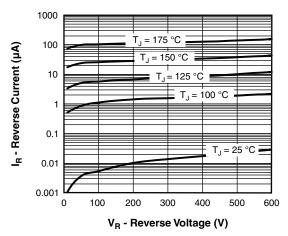


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

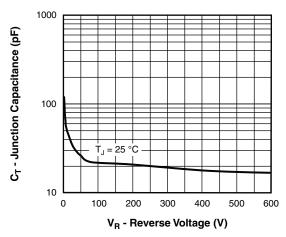


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

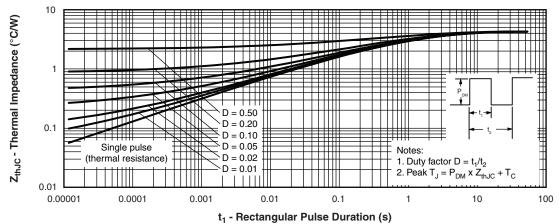


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

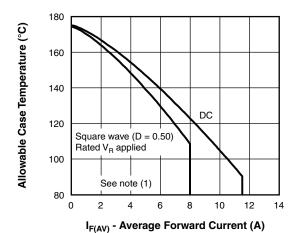


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

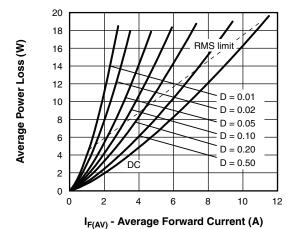


Fig. 6 - Forward Power Loss Characteristics

#### Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_{\text{C}} = T_{\text{J}} - (\text{Pd} + \text{Pd}_{\text{REV}}) \times R_{\text{thJC}}; \\ \text{Pd} = \text{forward power loss} = I_{\text{F(AV)}} \times V_{\text{FM}} \text{ at } (I_{\text{F(AV)}}/D) \text{ (see fig. 5)}; \\ \text{Pd}_{\text{REV}} = \text{inverse power loss} = V_{\text{R1}} \times I_{\text{R}} \text{ (1 - D)}; I_{\text{R}} \text{ at } V_{\text{R1}} = \text{rated } V_{\text{R}} \\ \end{array}$ 

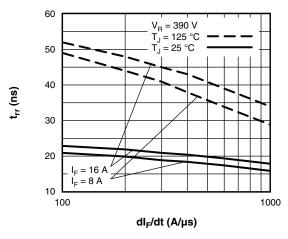


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

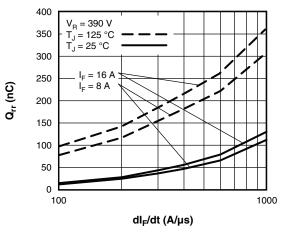
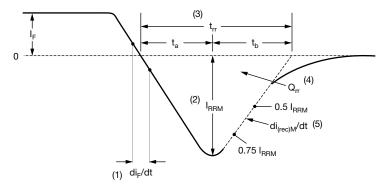


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt



- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3)  $\rm t_r$  reverse recovery time measured from zero crossing point of negative going  $\rm I_F$  to point where a line passing through 0.75  $\rm I_{RBM}$  and 0.50  $\rm I_{RBM}$  extrapolated to zero current.
- (4)  $\rm Q_{rr}$  area under curve defined by  $\rm t_{rr}$  and  $\rm I_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

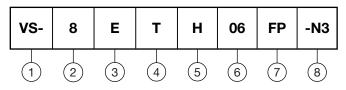
(5) di<sub>(rec)M</sub>/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

Fig. 9 - Reverse Recovery Waveform and Definitions



#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Current rating (8 = 8 A)

**3** - E = single

- T = TO-220, D<sup>2</sup>PAK (TO-263AB)

5 - H = hyperfast recovery

Voltage rating (06 = 600 V)

7 - FP = 2L TO-220 FullPAK

8 - Environmental digit:

-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

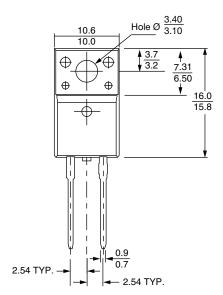
ORDERING INFORMATION (Example)				
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION	
VS-8ETH06FP-N3	50	1000	Antistatic plastic tube	

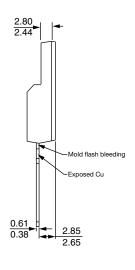
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?96157</u>				
Part marking information	www.vishay.com/doc?95392			

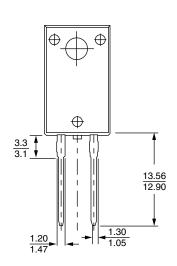


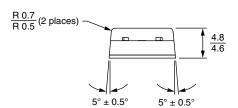
### 2L TO-220 FullPAK

#### **DIMENSIONS** in millimeters









Bottom view



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